

Supporting Information

Layered Indium-Silver-Based Hybrid Perovskite Single Crystals for High-Performance X-ray Detection

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Experimental Section

Materials

1,4-Butanediamine Dihydrobromide (BDABr₂; > 99.9%), bromargyrite (AgBr; > 99.9%), Indium bromide (InBr₃; > 99.9%), hydrobromic acid (HBr; 48% aqueous solution), were purchased from Aladdin. We confirm that all reagents and chemicals were used as received without further purification.

Crystal growth

BDA₂AgInBr₈: Add 0.16 g MABr and 0.518 g SnBr₂ to the PTFE-lined reactor vessel. Then add 3.5 mL hydrobromic acid and 0.5 mL hypophosphorous acid. Place in a 100°C forced air drying oven, maintain for 4 hours, then cool to 80°C at a rate of 1°C/h, followed by cooling to 30°C at a rate of 0.2°C/h.

Material Property Characterization

Power X-ray diffraction patterns were obtained on a Rigaku Miniflex600 diffractometer using Cu K α radiation (40 kV, 15 mA) with a step size of 0.02°. Crystal structure and orientation were determined on a Synergy Custom (Liquid MetalJet D2+). UV-visible absorption spectra in the 390-800 nm range were obtained using a Hitachi U4100UV spectrophotometer. Thermogravimetric analysis was performed on a Setaram Setsys16 thermogravimetric analyzer under a continuous nitrogen flow.

X-ray detection

A tungsten anode X-ray tube with 50 kV voltage (Moxtek TUB00154-W06) was used to provide a continuous X-ray, and a self-built chopper manufactured by lead sheets of 0.5 mm was used to produce a pulsed X-ray beam. A dosimeter (Radical AGDM+) with a Radical 10X6-180 ion chamber was used to calibrate X-ray dose rates, and 2 mm and 10 mm Aluminum plates as attenuators were employed to achieve a low dose rate. To provide the bias voltage and record current data, a computer-controlled source meter (Keithley Model 2450) with a test fixture (Keithley Model 8101-PIV) was employed. All X-ray experiments were performed in a dark, closed room (40-50 % relative humidity) that was controlled from outside the room by the researcher.

First-principles calculation

The density functional theory calculations were performed using the Vienna ab initio simulation package (VASP), including the effect of core electrons, were described using the projector augmented wave method. Perdew–Burke–Ernzerhf, generalized gradient approximation, and exchange-correlation functionals were used to relax the structural configurations and calculate the band structure. A plane-wave energy cutoff of 520 eV and a k-point mesh of $3\times 3\times 3$ was used in the electronic self-consistency. All structures were geometrically relaxed until the total force on each ion was below 0.01 eV \AA^{-1} . The K-points were defined as follows: Γ (0 0 0), X (0.5 0 0), Y (0 0.5 0), Z (0 0 0.5), R_2 (-0.5 -0.5 0.5), R_2 (-0.5 -0.5 0.5), T_2 (0 -0.5 0.5), U_2 (-0.5 0 0.5), V_2 (0.5 -0.5 0).

Figure Section

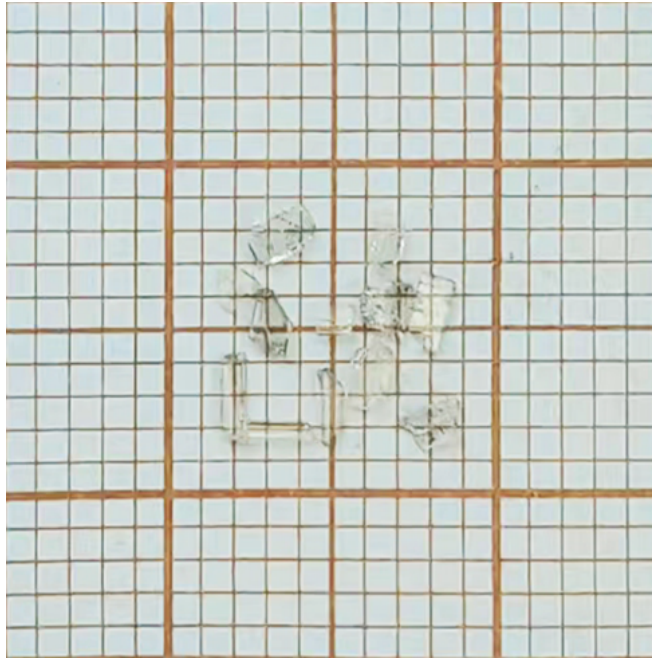


Figure S1. Photograph of BDA₂AgInBr₈ crystal.

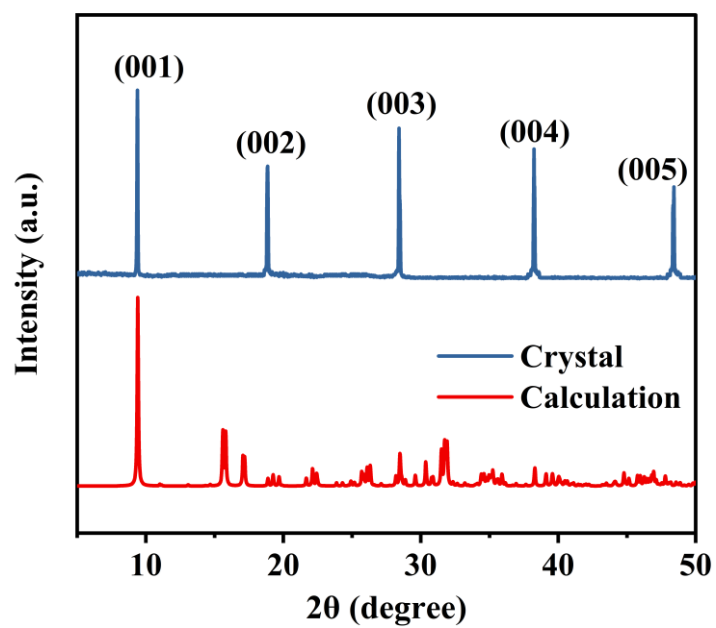


Figure S2. Single-crystal X-ray diffraction pattern of BDA₂AgInBr₈.

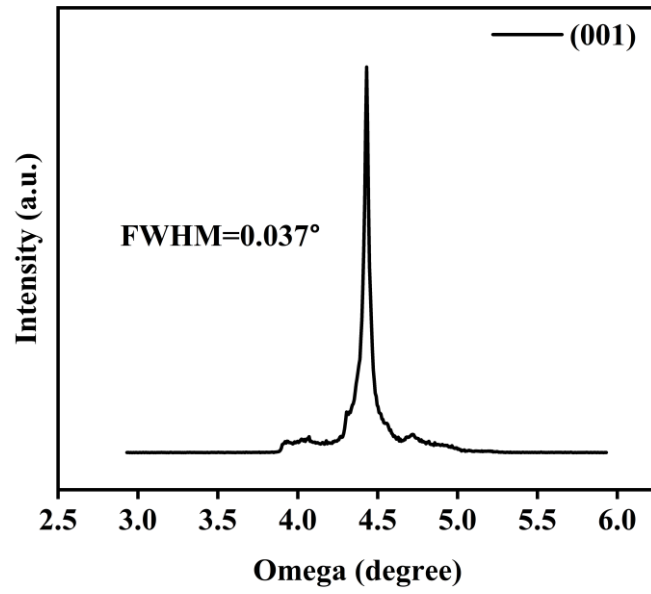


Figure S3. Rocking curve of the (001) diffraction peak for the BDA₂AgInBr₈ single crystal.

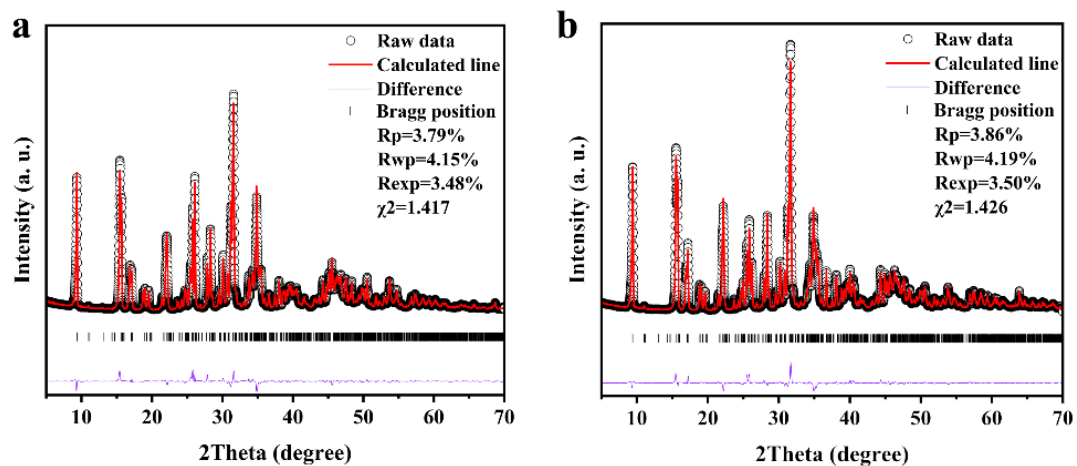


Figure S4. Rietveld refinement of powder XRD patterns for (a) freshly ground BDA₂AgInBr₈ sample and (b) sample stored at 80% relative humidity for 36 days.

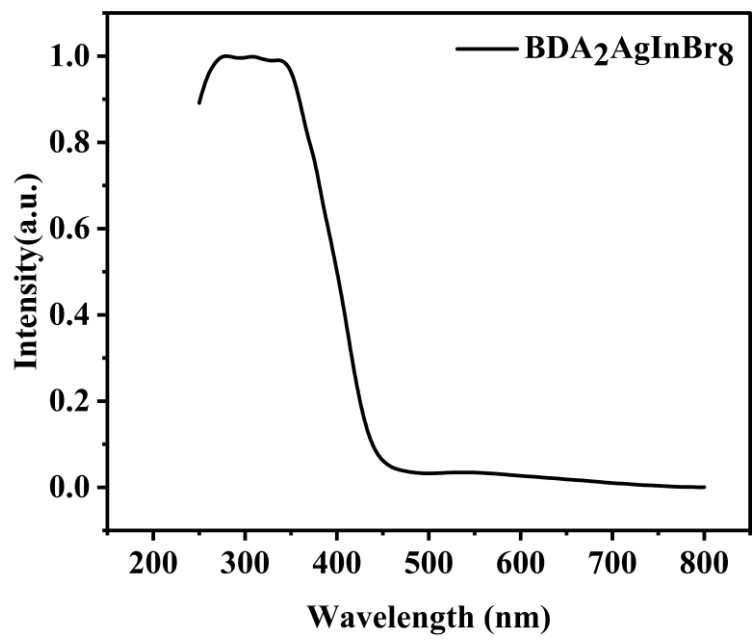


Figure S5. Ultraviolet absorption spectrum of BDA₂AgInBr₈ crystals.

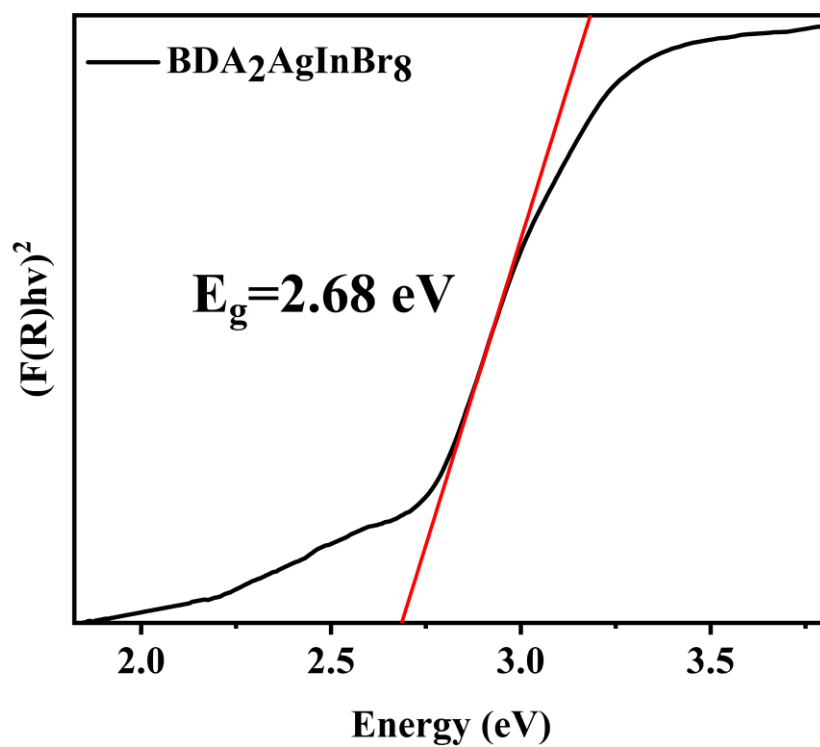


Figure S6. Optical bandgap of BDA₂AgInBr₈ crystals.

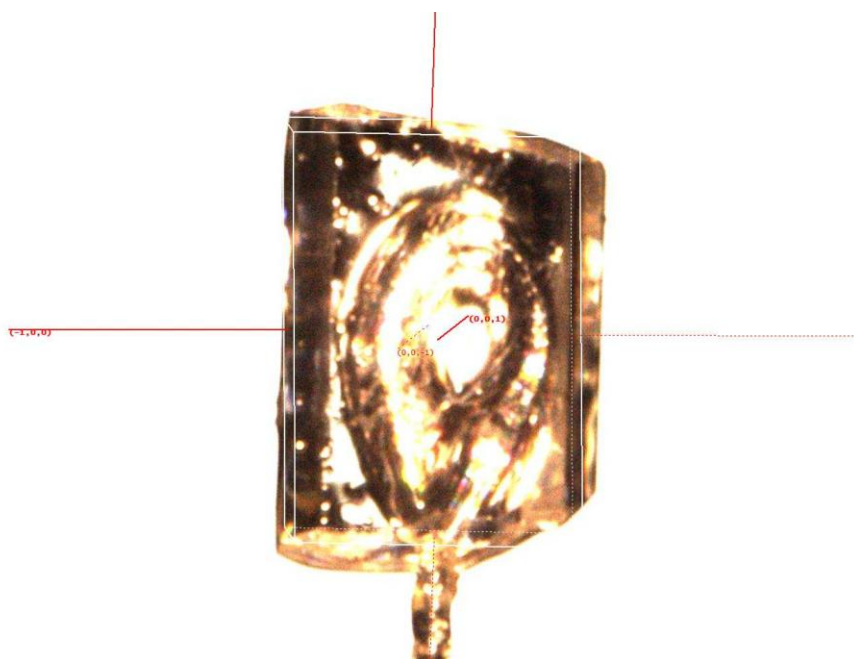


Figure S7. Photographic image of the orientation of BDA₂AgInBr₈ single crystals.

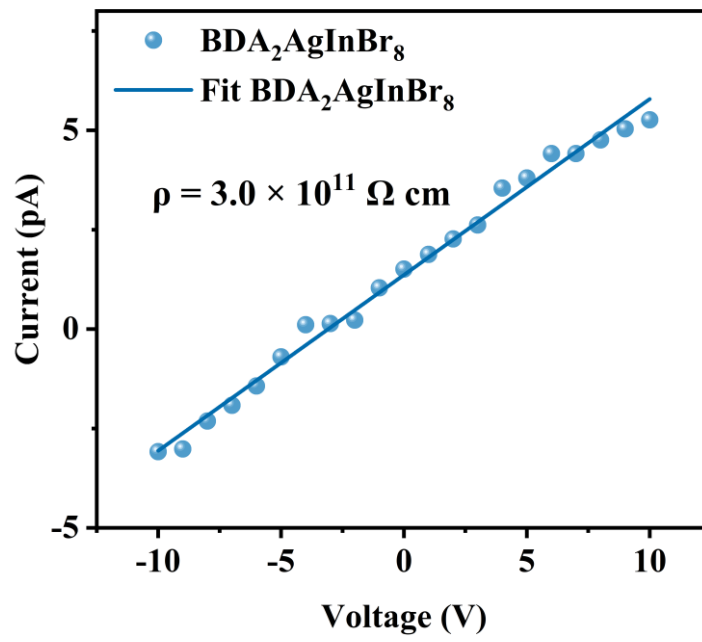


Figure S8. Resistivity of BDA₂AgInBr₈.

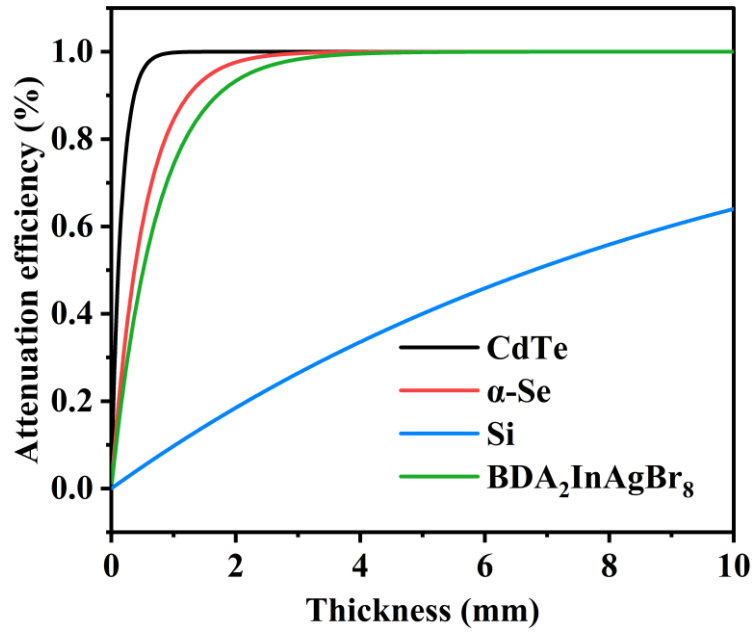


Figure S9. Attenuation efficiency of $\text{BDA}_2\text{AgInBr}_8$ at 50 keV.

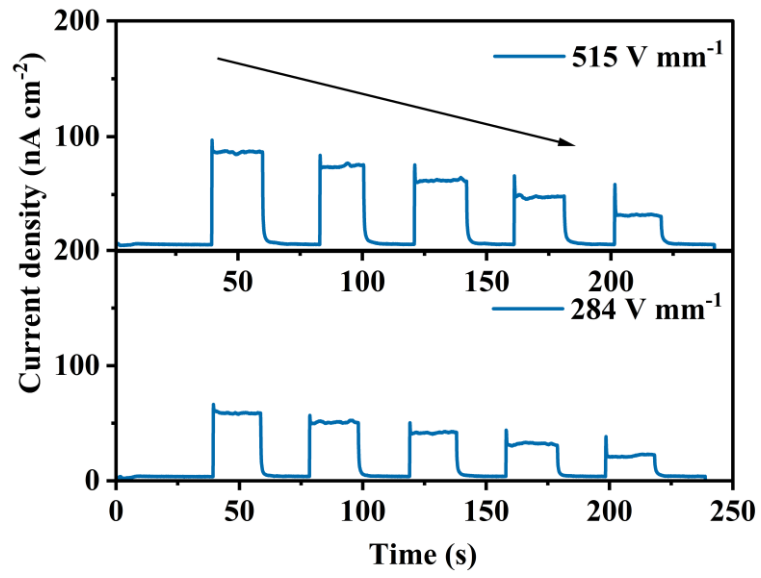


Figure S10. Photocurrent density of BDA₂AgInBr₈ under different dose rates.

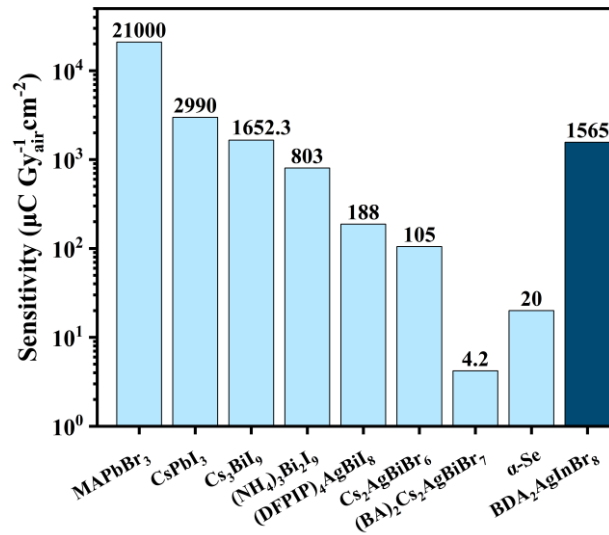


Figure S11. The comparison of sensitivity among commercial scintillation semiconductors, lead-based perovskites, and lead-free perovskites.

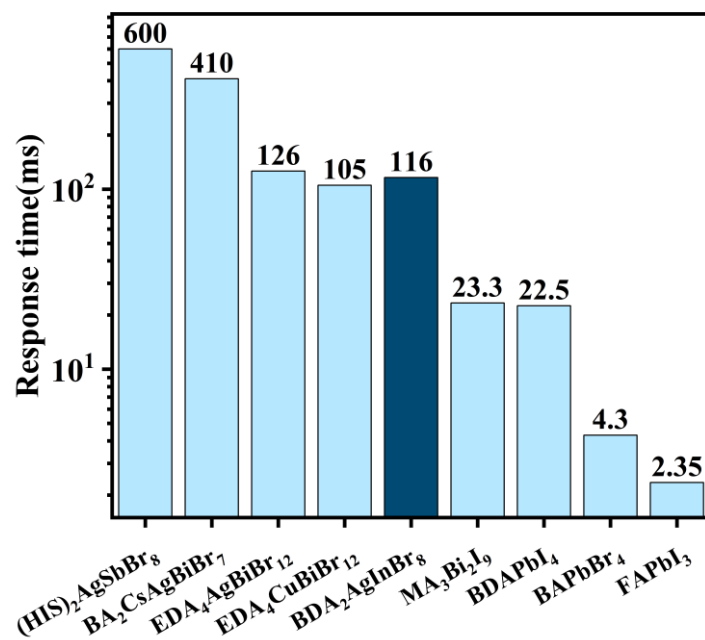


Figure S12. Response time comparison of BDA₂AgInBr₈ with other lead-free perovskites and representative lead-based perovskites.

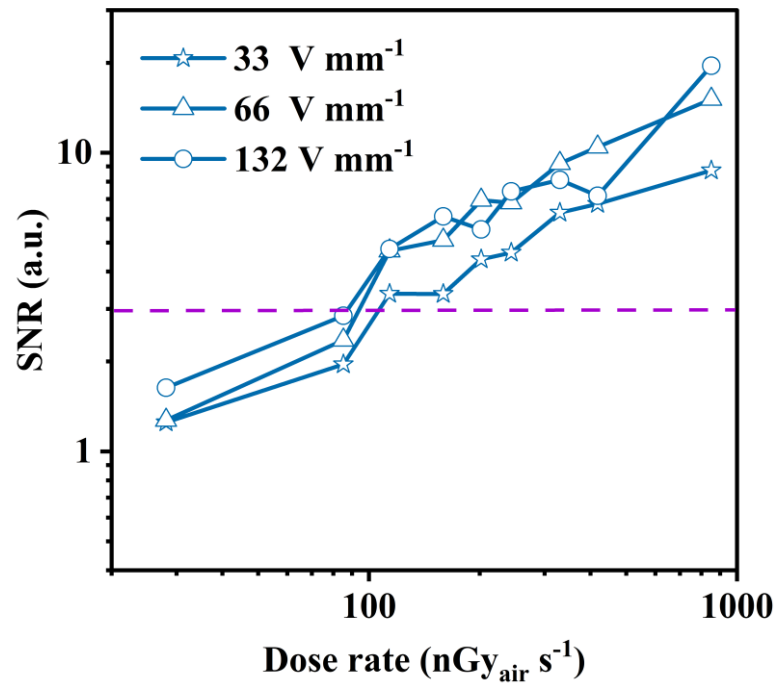


Figure S13. Signal-to-noise ratio (SNR) of $\text{BDA}_2\text{AgInBr}_8$ under different dose rates and electric field strengths.

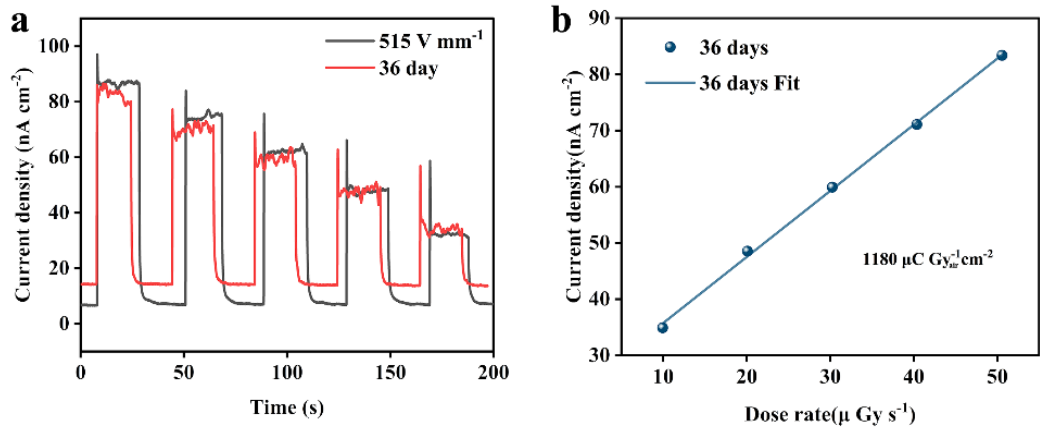


Figure S14. X-ray detection performance of detector after storage at 25 °C and 60% relative humidity for 36 days. (a) Time-dependent current density response under intermittent X-ray irradiation at an electric field of 515 V mm⁻¹. (b) Linear fit of current density versus X-ray dose rate.

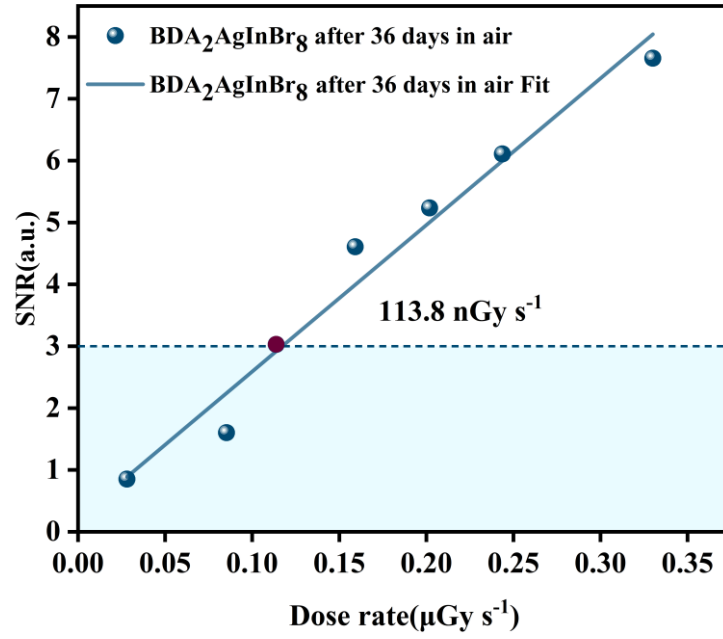


Figure S15. Signal-to-noise ratio of BDA₂AgInBr₈ under different dose rates after 36 days of exposure at 25 °C and 60% relative humidity.

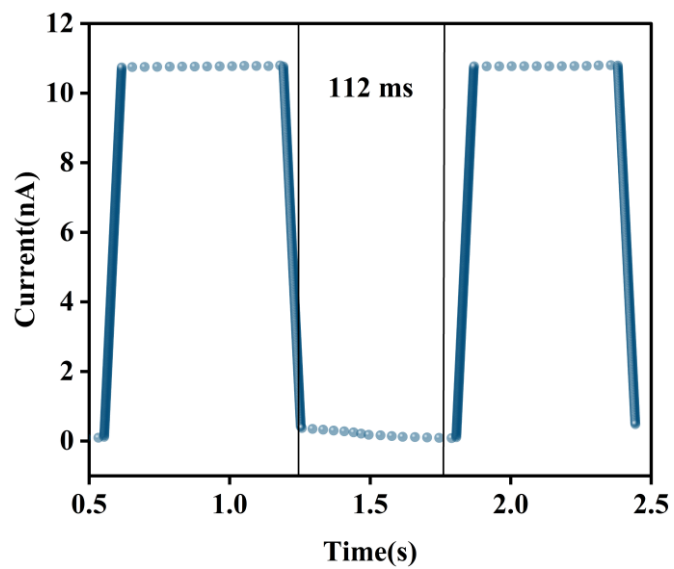


Figure S16. Time-resolved photocurrent response of BDA₂AgInBr₈ after 36 days of exposure at 25 °C and 60% relative humidity.

Table Section

Table S1. Crystal data of BDA₂AgInBr₈.

Compound	BDA₂AgInBr₈
Empirical	(NH ₃ (CH ₂) ₄ NH ₃) ₂ AgInBr ₈
Formula weight	1042.31
Crystal system	Triclinic
Space group	P $\bar{1}$
a (Å)	8.03130(10)
b(Å)	8.08910(10)
c (Å)	9.59210(10)
α (deg)	101.6290(10)
β (deg)	91.2930(10)
γ (deg)	90.4610(10)
V (Å³)	610.163(12)
Z	1
ρ (calcd) (g/cm³)	2.837
μ (mm⁻¹)	20.001
GOF on F^2	1.062
R₁/wR₂[F_o $2 > 2\sigma(F_o^2)$]^a	0.0181/0.0443
R₁/wR₂ (all data)	0.0187/0.0446

$$R_1(F) = \sum ||F_o| - |F_c|| / \sum |F_o|; wR_2(F_o^2) = [\sum w(F_o^2 - F_c^2)^2 / \sum w(F_o^2)^2]^{1/2}$$

Table S2. Electronic band structure with or without spin-orbit coupling effect (SOC)

Compound		without SOC			With SOC	
	Band gap value	VBM	CBM	Band gap value	VBM	CBM
BDA ₂ AgInBr ₈	1.8205	R ₂	X	1.8158	R ₂	X

Table S3. Crystal data of BDA₂AgInBr₈.

Materials	Sensitivity ($\mu\text{CGy}^{-1}\text{cm}^{-2}$)	Detection Limits (μGys^{-1})	rise time (ms)	fall time (ms)
(BA) ₂ PbI ₄ SC ^[1]	148	0.241	4.5	4.3
BA ₂ PbBr ₄ SC ^[2]	726.18	0.0082	3.2	3.5
PEA ₂ PbBr ₄ film ^[3]	806	0.042	0.147±0.010	0.768±0.109
(F-PEA) ₂ PbI ₄ SC ^[4]	3402	0.023	—	—
BA ₂ EA ₂ Pb ₃ Br ₁₀ SC ^[5]	6800	5.5	—	—
(BA) ₂ (MA) ₂ Pb ₃ I ₁₀ film ^[6]	2.76×10 ⁵	10	<0.0005	0.02-0.06
(C ₄ H ₉ NH ₃) ₂ PbBr ₄ SC ^[7]	236	22.7	—	<100
BDA ₂ AgInBr ₈ SC (our work)	1565	120		116

Reference

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